

STR7000+SI-8020 Series

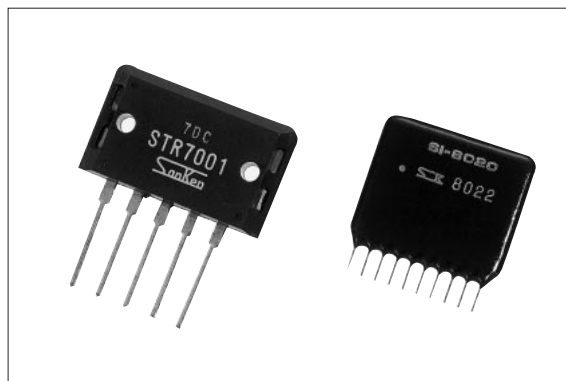
Separate Excitation Switching Type

■Features

- High output current (6A:STR7000 series, 12A: STR7100 series)
- High efficiency (70 to 90%)
- Wide DC input voltage range
- Built-in drooping type overcurrent protection circuit
- Foldback type overcurrent protection can be set externally.
- Output voltage adjustment
- Built-in reference oscillator (35kHz)
- Output ON/OFF control

■Applications

- Electronic equipment



■Lineup

I_o (A) \ V_o (V)	5	12	15	24
6	STR7001+SI-8020	STR7002+SI-8021	STR7002+SI-8022	STR7003+SI-8023
12	STR7101+SI-8020	STR7102+SI-8021	STR7102+SI-8022	STR7103+SI-8023

■Absolute Maximum Ratings

Power Section: STR7000/STR7100 ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Ratings		Unit
		STR7000 Series	STR7100 Series	
Power Transistor Breakdown Voltage	V_{4-1}	60		V
Drive Transistor Breakdown Voltage	V_{4-5}	60		V
Diode Breakdown Voltage	V_{1-2}	60		V
Collector Current	I_c	6(peak 7.5)	12(peak 15)	A
Power Dissipation	P_{D1}	100($T_c=25^\circ\text{C}$)	125($T_c=25^\circ\text{C}$)	W
	P_{D2}	4.3(Without heatsink)		W
Power Transistor Thermal Resistance	$R_{th(j-c)}$	1.25	1.0	$^\circ\text{C/W}$
Power Transistor Junction Temperature	T_j	+150		$^\circ\text{C}$
Operating Temperature	T_{OP}	-30 to +125(T_c)		$^\circ\text{C}$
Storage Temperature	T_{Stg}	-30 to +125		$^\circ\text{C}$

■Control Section: SI-8020 Series ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Ratings	Unit
DC Input Voltage	V_{IN}	55	V
Power Dissipation	P_D	1	W
Operating Temperature	T_{OP}	-20 to +85	$^\circ\text{C}$
Storage Temperature	T_{Stg}	-20 to +100	$^\circ\text{C}$

■Electrical Characteristics: 6A Type

(T_a=25°C)

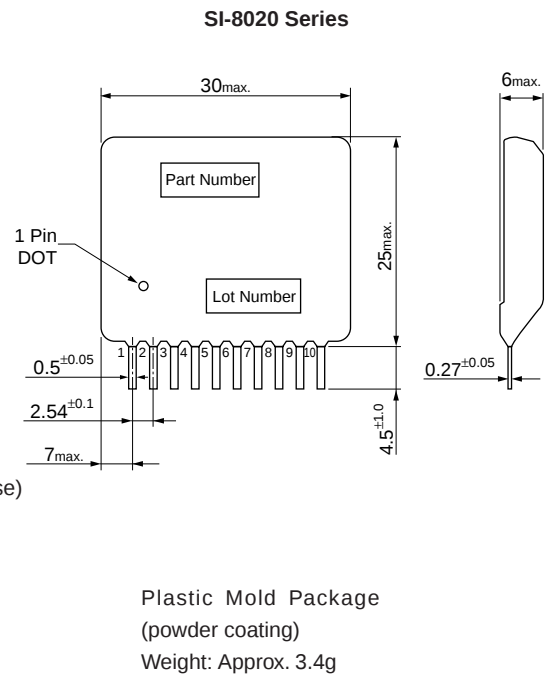
Parameter	Symbol	Ratings												Unit
		STR7001+SI-8020			STR7002+SI-8021			STR7002+SI-8022			STR7003+SI-8023			
		min.	typ.	max.	min.	typ.	max.	min.	typ.	max.	min.	typ.	max.	
DC Input Voltage Range	V _{IN}	11		40	18		50	21		50	30		50	V
Output Voltage	V _O	5.0	5.1	5.2	11.8	12.0	12.2	14.8	15.0	15.2	23.7	24.0	24.3	V
	Conditions	V _{IN} =20V, I _o =3.0A			V _{IN} =27V, I _o =3.0A			V _{IN} =30V, I _o =3.0A			V _{IN} =40V, I _o =3.0A			
Efficiency	η		72			84			86			90		%
	Conditions	V _{IN} =20V, I _o =3.0A			V _{IN} =27V, I _o =3.0A			V _{IN} =30V, I _o =3.0A			V _{IN} =40V, I _o =3.0A			
Switching Frequency	f		35			35			35			35		kHz
	Conditions	V _{IN} =20V, I _o =3.0A			V _{IN} =27V, I _o =3.0A			V _{IN} =30V, I _o =3.0A			V _{IN} =40V, I _o =3.0A			
Line Regulation	ΔV _{OLINE}			80			120			150			200	mV
	Conditions	V _{IN} =15 to 25V, I _o =3.0A			V _{IN} =22 to 32V, I _o =3.0A			V _{IN} =25 to 35V, I _o =3.0A			V _{IN} =35 to 45V, I _o =3.0A			
Load Regulation	ΔV _{OLOAD}			30			40			40			50	mV
	Conditions	V _{IN} =20V, I _o =1 to 5A			V _{IN} =27V, I _o =1 to 5A			V _{IN} =30V, I _o =1 to 5A			V _{IN} =40V, I _o =1 to 5A			
Ripple Rejection	R _{REJ}		45			45			45			45		dB
	Conditions	f=100 to 120Hz			f=100 to 120Hz			f=100 to 120Hz			f=100 to 120Hz			
Overcurrent Protection Starting Current	I _{S1}	6.0		7.5	6.0		7.5	6.0		7.5	6.0		7.5	A
Limited Current at Overcurrent Protection Operation	I _{S2}	6.0		7.5	6.0		7.5	6.0		7.5	6.0		7.5	A
	Conditions	R _S =0.02Ω			R _S =0.02Ω			R _S =0.02Ω			R _S =0.02Ω			

■Electrical Characteristics: 12A Type

(T_a=25°C)

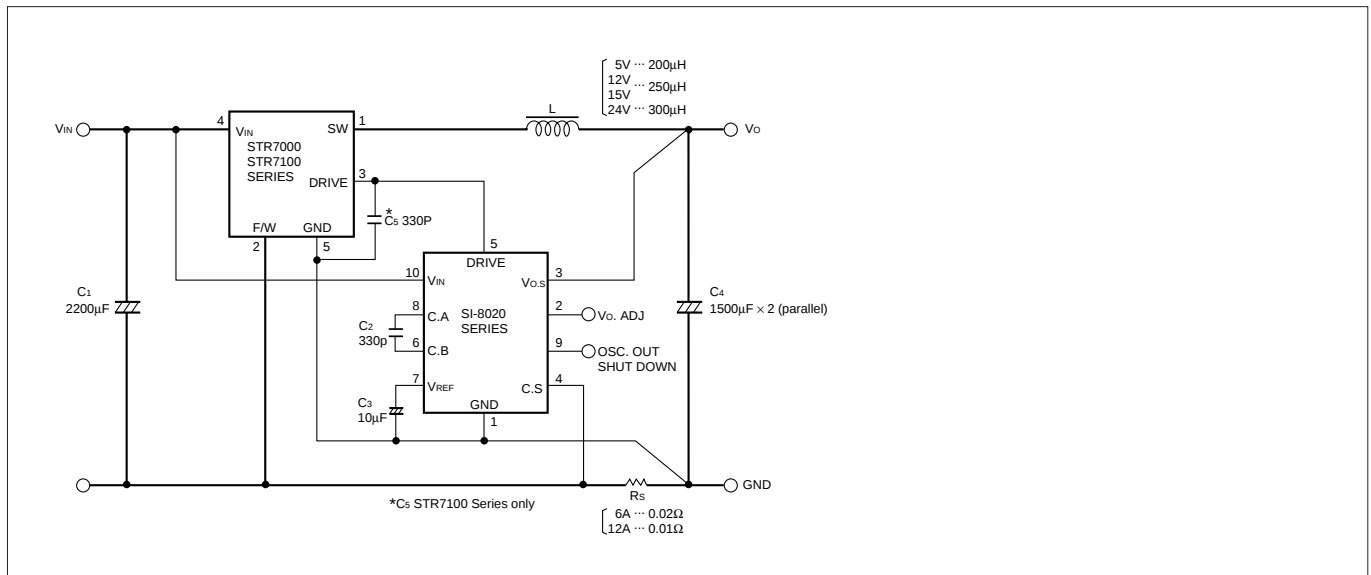
Parameter	Symbol	Ratings												Unit
		STR7101+SI-8020			STR7102+SI-8021			STR7102+SI-8022			STR7103+SI-8023			
		min.	typ.	max.	min.	typ.	max.	min.	typ.	max.	min.	typ.	max.	
DC Input Voltage Range	V _{IN}	11		40	18		50	21		50	30		50	V
Output Voltage	V _O	5.0	5.1	5.2	11.8	12.0	12.2	14.8	15.0	15.2	23.7	24.0	24.3	V
	Conditions	V _{IN} =20V, I _O =6.0A			V _{IN} =27V, I _O =6.0A			V _{IN} =30V, I _O =6.0A			V _{IN} =40V, I _O =6.0A			
Efficiency	η		70			82			84			87		%
	Conditions	V _{IN} =20V, I _O =6.0A			V _{IN} =27V, I _O =6.0A			V _{IN} =30V, I _O =6.0A			V _{IN} =40V, I _O =6.0A			
Switching Frequency	f		35			35			35			35		kHz
	Conditions	V _{IN} =20V, I _O =6.0A			V _{IN} =27V, I _O =6.0A			V _{IN} =30V, I _O =6.0A			V _{IN} =40V, I _O =6.0A			
Line Regulation	ΔV _{OLINE}			80			120			150			200	mV
	Conditions	V _{IN} =15 to 25V, I _O =6.0A			V _{IN} =22 to 32V, I _O =6.0A			V _{IN} =25 to 35V, I _O =6.0A			V _{IN} =35 to 45V, I _O =6.0A			
Load Regulation	ΔV _{OLOAD}			30			40			40			50	mV
	Conditions	V _{IN} =20V, I _O =3 to 9A			V _{IN} =27V, I _O =3 to 9A			V _{IN} =30V, I _O =3 to 9A			V _{IN} =40V, I _O =3 to 9A			
Ripple Rejection	R _{REJ}		45			45			45			45		dB
	Conditions	f=100 to 120Hz			f=100 to 120Hz			f=100 to 120Hz			f=100 to 120Hz			
Overcurrent Protection Starting Current	I _{S1}	12		15	12		15	12		15	12		15	A
Limited Current at Overcurrent Protection Operation	I _{S2}	12		15	12		15	12		15	12		15	A
	Conditions	R _S =0.01Ω			R _S =0.01Ω			R _S =0.01Ω			R _S =0.01Ω			

(unit: mm)



The image contains two circuit diagrams. The left diagram is for the STR7000/7100 Series, showing a power MOSFET driver circuit with pins for VIN, SW.OUT, DRIVE, GND, and F.WHEEL. The right diagram is for the SI-8020 Series, a more complex IC with multiple functional blocks including a voltage reference, dead time generator, PWM comparator, and two current amplifiers (Io AMP and Vo AMP), with pins for VREF, DRIVE, GND, Vo ADJ, Vo.SENSE, and various compensation and current sense pins.

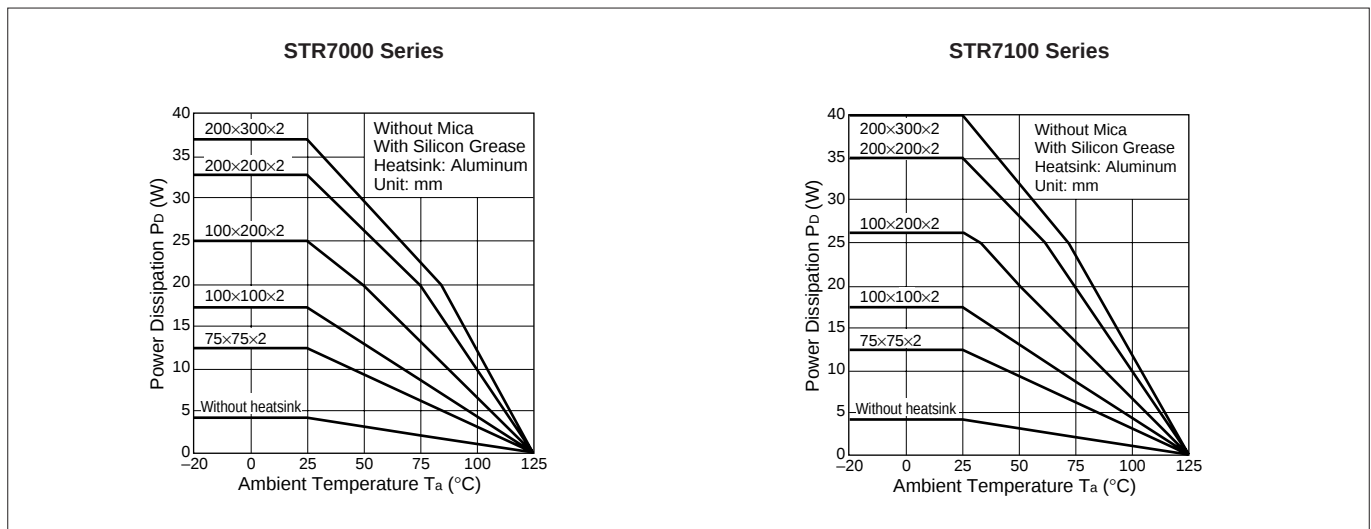
Standard External Circuit



Notes of Pattern Design

- 1) Thick lines in the Standard External Circuit are lines through which a large current flows. Make these pattern lines as thick as possible.
- 2) Place capacitor C_1 on the input side as closely as possible to terminals no.2 and no.4 of the STR7000/7100 series. C_1 may be used in combination with a smoothing capacitor for rectifying, but the above points must be taken into consideration. In cases where C_1 is not provided or it is placed too far from the terminals stated above, abnormal oscillation due to poorer transient response or increased ringing may occur.
- 3) Connect voltage sensing terminal $V_{O.S}$ and GND as closely as possible to output capacitor C_4 (a current of approximately 1mA flows into the $V_{O.S}$ terminal). If they are placed too far from C_4 , abnormal oscillation due to decreased regulation or increased switching ripple may occur.
- 4) Connect current sensing terminal C.S and GND as closely as possible to the detection resistor R_s (a current of approximately 0.5mA flows from the CS terminal).
If they are placed too far from R_s , a decrease of the overcurrent setting point due to the voltage drop in the pattern, or malfunction of the protection circuit due to increased ringing may occur.

T_a - P_D Characteristics

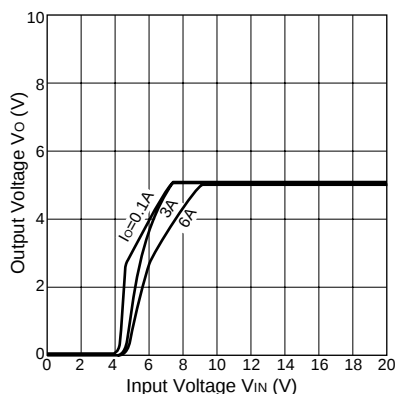


■Typical Characteristics

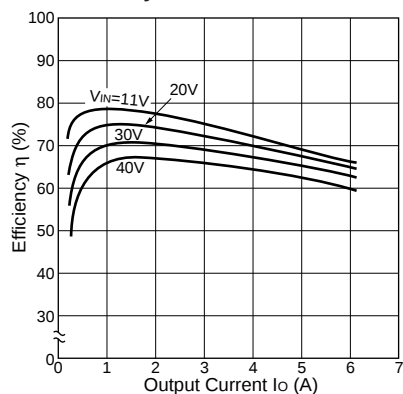
($T_a=25^\circ\text{C}$)

STR7001+SI-8020(5V)

Rise Characteristics

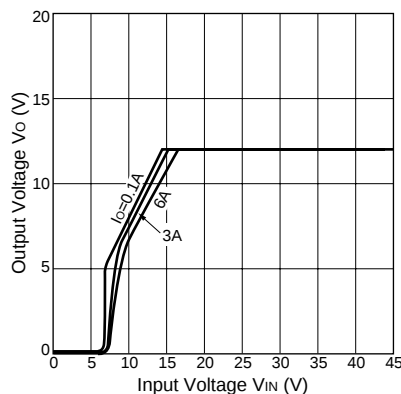


Efficiency Characteristics

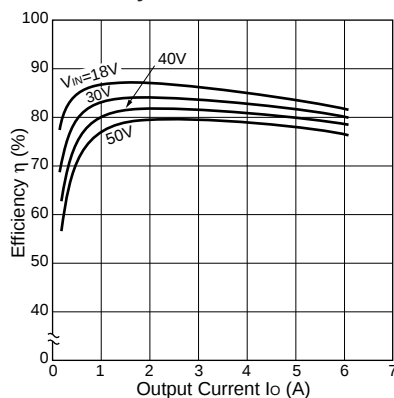


STR7002+SI-8021(12V)

Rise Characteristics

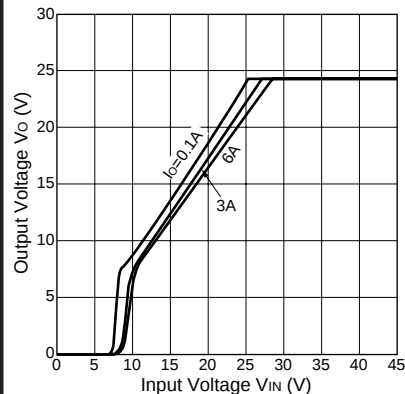


Efficiency Characteristics

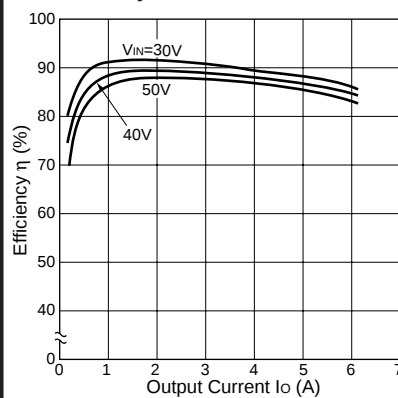


STR7003+SI-8023(24V)

Rise Characteristics

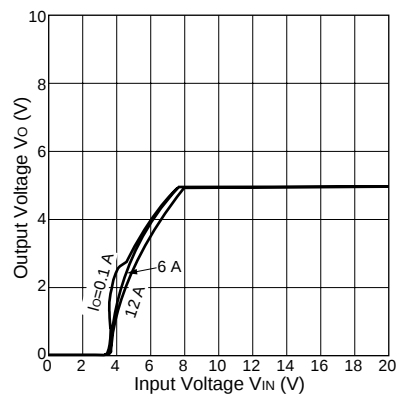


Efficiency Characteristics

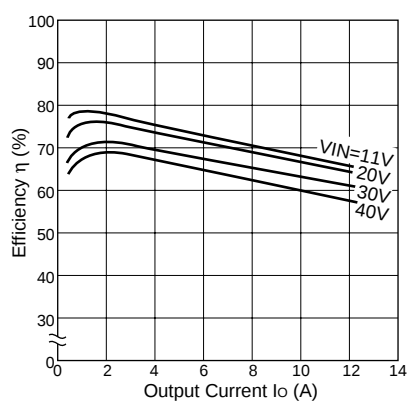


STR7101+SI-8020(5V)

Rise Characteristics

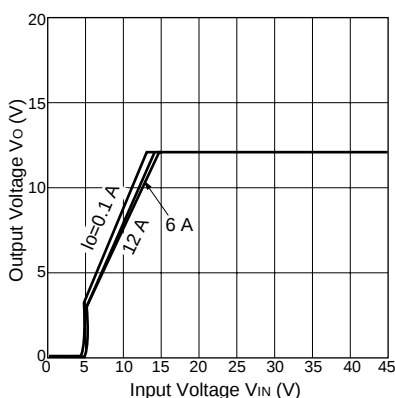


Efficiency Characteristics

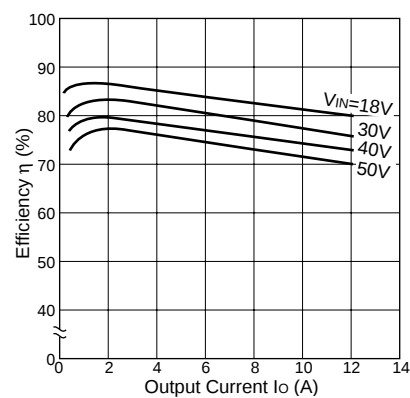


STR7102+SI-8021(12V)

Rise Characteristics

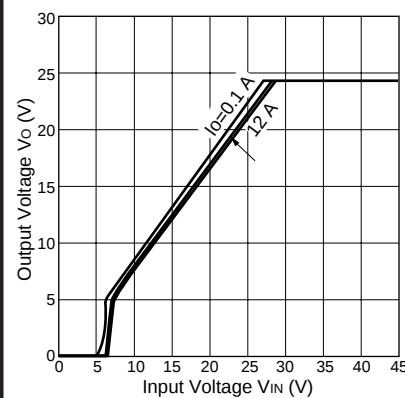


Efficiency Characteristics

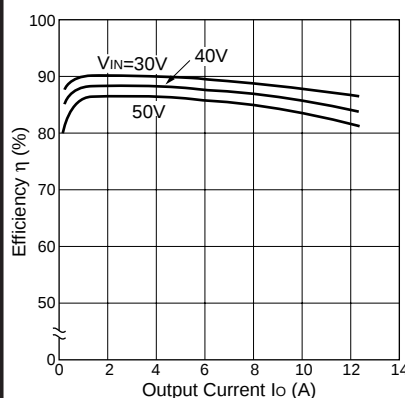


STR7103+SI-8023(24V)

Rise Characteristics



Efficiency Characteristics



Copyright © Each Manufacturing Company.

All Datasheets cannot be modified without permission.

This datasheet has been download from :

www.AllDataSheet.com

100% Free DataSheet Search Site.

Free Download.

No Register.

Fast Search System.

www.AllDataSheet.com